



Attorney's Docket No. 07977-242001 / US3586

THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant : Ohnuma, et al. Art Unit : 1765
Serial No.: 09/050,182 Examiner : R. Kunemund
Filed : March 26, 1998
Title : METHOD OF MANUFACTURING A SEMICONDUCTOR DEVICE

BOX AF
Commissioner for Patents
Washington, D.C. 20231

RESPONSE

In response to the action mailed April 3, 2001, please
amend the application as follows:

In the claims:

Please amend claims 1, 9, 17, 25, 45 and 52 as follows:

Sub D
1. (Three Times Amended) A method of manufacturing a
semiconductor device including at least a thin film transistor,
said method comprising the steps of:
forming an amorphous semiconductor film comprising
silicon over a substrate;

CERTIFICATE OF MAILING BY FIRST CLASS MAIL

I hereby certify under 37 CFR §1.8(a) that this correspondence is being deposited with the United States Postal Service as first class mail with sufficient postage on the date indicated below and is addressed to the Commissioner for Patents, Washington, D.C. 20231.

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